

ZX5T949G

30V PNP LOW SATURATION TRANSISTOR IN SOT223

Features

- BV_{CEO} > -30V
- I_C = -5.5A High Continuous Collector Current
- I_{CM} = -20A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)}
- Exceptional Gain Linearity down to -10mA
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free "Green" Device (Note 3)
- · Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads;
 Solderable per MIL-STD-202, Method 208@3
- Weight: 0.112 grams (Approximate)

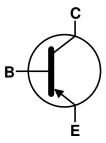
Applications

- DC-DC Converters
- MOSFET Gate Drivers
- Charging Circuits
- Power Switches

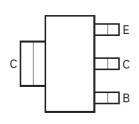








Device Symbol



Top View Pin-Out

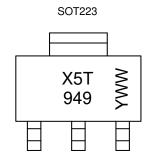
Ordering Information (Notes 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T949GTA	AEC-Q101	X5T949	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



X5T 949 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-30	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-5.5	Α
Peak Pulse Current	I _{CM}	-20	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)		3.0 24	W mW /°C
Linear Derating Factor	(Note 6)	P _D	1.6 12.8	
Thermal Designation to Ambient	(Note 5)	$R_{\theta JA}$	42	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	78	°C/W
Thermal Resistance Junction to Lead (Note 7)		$R_{ heta JL}$	8.84	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3B
Electrostatic Discharge - Machine Model	ESD MM	400	٧	С

Notes:

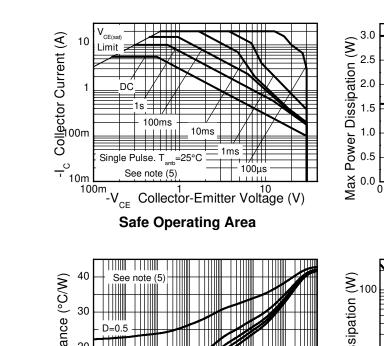
- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

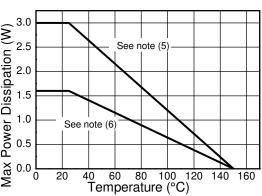
November 2015

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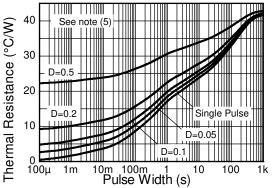


Thermal Characteristics and Derating Information

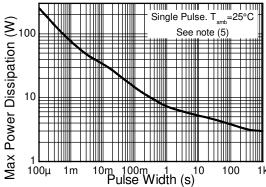




Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

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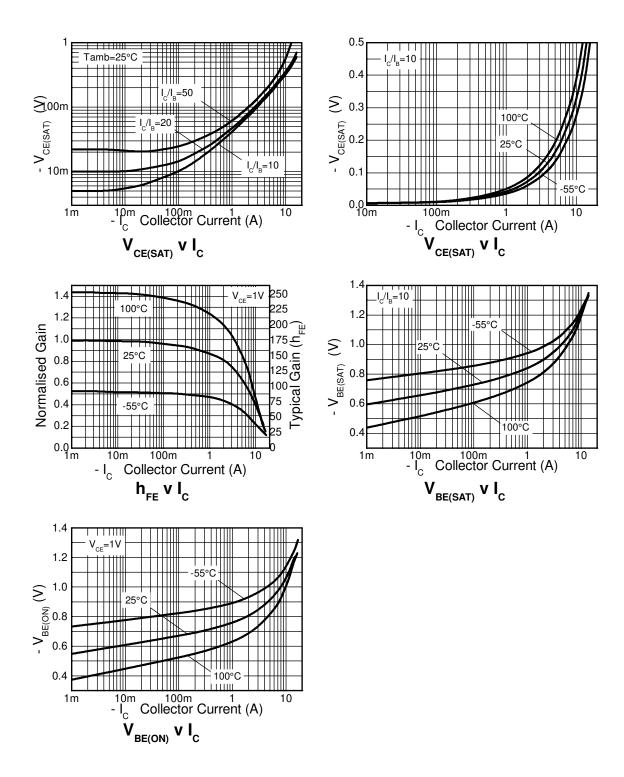
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	-50	-70	-	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CER}	-50	-70	-	V	$I_C = -1\mu A, R_B \leq 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-30	-40	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	-	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	=	<1	-20 -0.5	nA ^	V _{CB} = -40V
		-	-		μA	$V_{CB} = -40V, T_A = +100^{\circ}C$
Collector Cut-Off Current	l _{CER} R ≤1kΩ	-	<1	-20 -0.5	nA μA	$V_{CB} = -40V$
F	·		-			$V_{CB} = -40V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}	-	<1	-10	nA	$V_{EB} = -6V$
		100	225	-	-	$I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$
DC Current Transfer Static Ratio (Note 9)	h	100	200	300		$I_C = -1A$, $V_{CE} = -1V$
DC Current Transfer Static Hallo (Note 9)	h _{FE}	70	145	-		$I_C = -5A$, $V_{CE} = -1V$
		10	20	-		I _C = -20A, V _{CE} = -1V
	V _{CE} (sat)	-	-30	-45	mV	$I_C = -0.5A$, $I_B = -20mA$
		-	-40	-60		I _C = -1A, I _B = -100mA
Collector-Emitter Saturation Voltage (Note 9)		-	-60	-85		$I_C = -1A$, $I_B = -20mA$
		-	-70	-90		$I_C = -2A$, $I_B = -200mA$
			-170	-210		$I_C = -5.5A$, $I_B = -500mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	-1,030	-1,130	mV	$I_C = -5.5A$, $I_B = -500mA$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	-	-900	-1,000	mV	$I_C = -5.5A$, $V_{CE} = -1V$
Transitional Frequency (Note 9)	f _T	-	110	=	MHz	$I_C = -100 \text{mA}, V_{CE} = -10 \text{V},$ f = 50 MHz
Output Capacitance	C_{obo}	-	83	-	pF	V _{CB} = -10V, f = 1MHz
Switching Time	t _{ON}	-	43	-	nc	$V_{CC} = -10V, I_{C} = -1A,$
Switching Time	toff	-	230	-	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leqslant 300 μ s. Duty cycle \leqslant 2%.



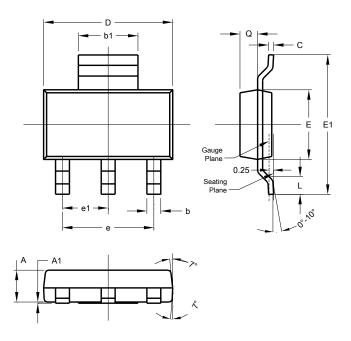
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

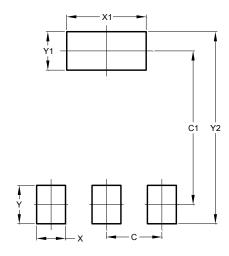
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
C	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Υ	1.60
Y1	1.60
Υ2	8 00



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